DS04-23505-1E

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# ASSP

**CMOS** 

# FRONT-END LSI

# MB54501

#### **■** DESCRIPTION

The Fujitsu MB54501 includes a low-noise amplifier and a mixer, which are used for front end of mobile telecommunication systems.

Using Fujitsu's advanced technology, MB54501 achieves an Icc of 6.0mA (typ.).

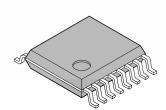
#### **■ FEATURES**

	Amplifier	Mixer
Supply voltage	3V (typ.)	3V (typ.)
<ul> <li>Current consumption</li> </ul>	3mA (typ.)	3mA (typ.)
<ul> <li>Input frequency</li> </ul>	1.1GHz (max.)	1.1GHz (max.)
• Gain	14dB (typ.)*1	15dB (typ.)*2
<ul> <li>Noise figure</li> </ul>	2.2dB (typ.)*1	5dB (SSB, typ.)*2
<ul> <li>1dB compression point</li> </ul>	-1dBm (typ.)*1	
Input return loss	8dB (typ.)*1	
Output return loss	10dB (typ.)*1	
*1: Measured by the circuit (fin = 878MHz)		
*2: Measured by the circuit (IF = 90MHz)	of "measurement circ	uit example".

• 16-pin Plastic Shrink Small Outline Package (Suffix: -PFV)

#### **■ PACKAGE**

16-pin Plastic SSOP

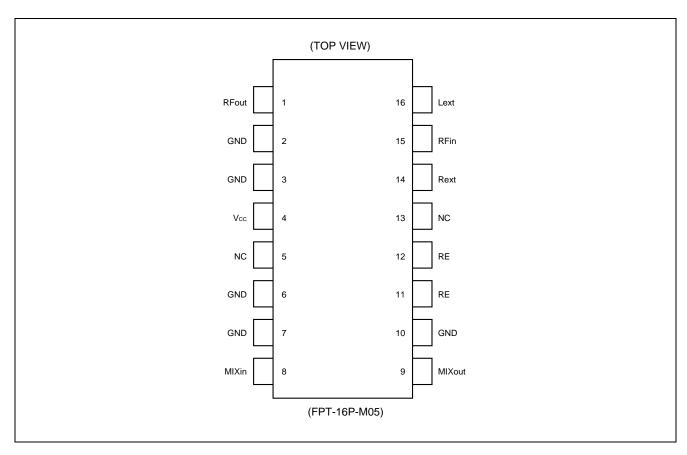


(FPT-16P-M05)



# MB54501

## **■ PIN ASSIGNMENT**

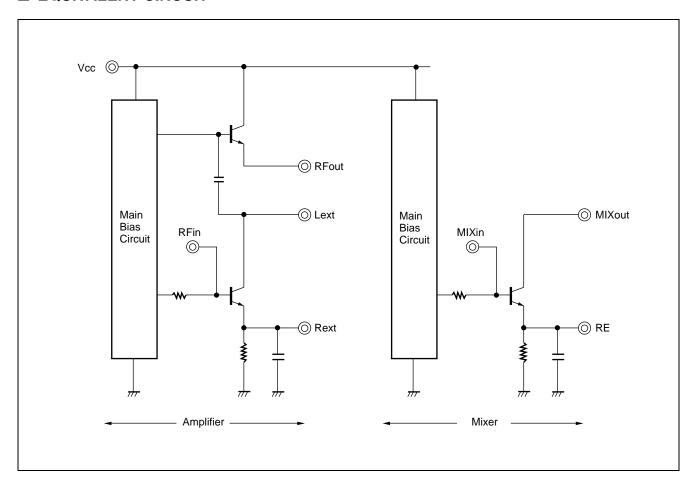


#### ■ ABSOLUTE MAXIMUM RATINGS

Parameters	Symbol	Value	Unit
Supply Voltage	Vcc	-0.5 to 7.0	V
Output Voltage	Vo	−0.5 to Vcc + 0.5	V
Output Current	lo	0 to 10	mA
Storage Temperature	Тѕтс	-55 to +125	°C

Note: Permanent device damage may occur if the above Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **■ EQUIVALENT CIRCUIT**



## **■ PIN DESCRIPTION**

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description	
1	RFout	Amplifier output	9	MIXout	Mixer output	
2	GND	Ground	10	GND	Ground	
3	GND	Ground	11	RE	Emitter of a transistor for mixer	
4	Vcc	Power supply	12	KE	Emilier of a transistor for mixer	
5	NC	No connection	13	NC	No connection	
6	GND	Ground	14	Rext	Emitter of a transistor for amplifier	
7	GND	Ground	15	RFin	Amplifier input	
8	MIXin	Mixer input	16	Lext	Amplifier load connection	

# MB54501

### **■ RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol		Unit		
Parameter	Symbol	Min.	Тур.	Max.	Unit
Supply Voltage	Vcc	2.7	3.0	5.5	V
Input Voltage	Vı	GND	_	Vcc	V
Operating Temperature	Та	-40	_	+85	°C

Notes: To protect against damage by electrostatic discharge, note the following handling precautions:

- Store and transport devices in conductive containers.
- Use properly grounded workstations, tools, and equipment.
- Turn off power before inserting or removing this device into or from a socket.
- Protect leads with conductive sheet, when transporting a board mounted device.

### **■ ELECTRICAL CHARACTERISTICS**

#### **AMPLIFIER**

 $(Vcc = +3.0V, Ta = 25^{\circ}C)$ 

Parameter	Symbol	Conditions	Target Value			Unit
			Min.	Тур.	Max.	Onit
Supply Voltage	Vcc		2.7	3.0	5.5	V
Supply Current	Icc			3.0		mA
Operating Frequency	fin			878	1100	MHz
Gain	Gain	_		14	_	dB
Noise Figure	NF			2.2		dB
1dB Compression Point	P <sub>1dB</sub>	Output		-1		dBm
Input Return Loss	RLin	_		8	_	dB
Output Return Loss	RLоит	_		10	_	dB

**Remark:** Electrical characteristics depend on external circuits (elements) or status of mounting. The above characteristics are measured by the test circuit in the next page.

#### **MIXER**

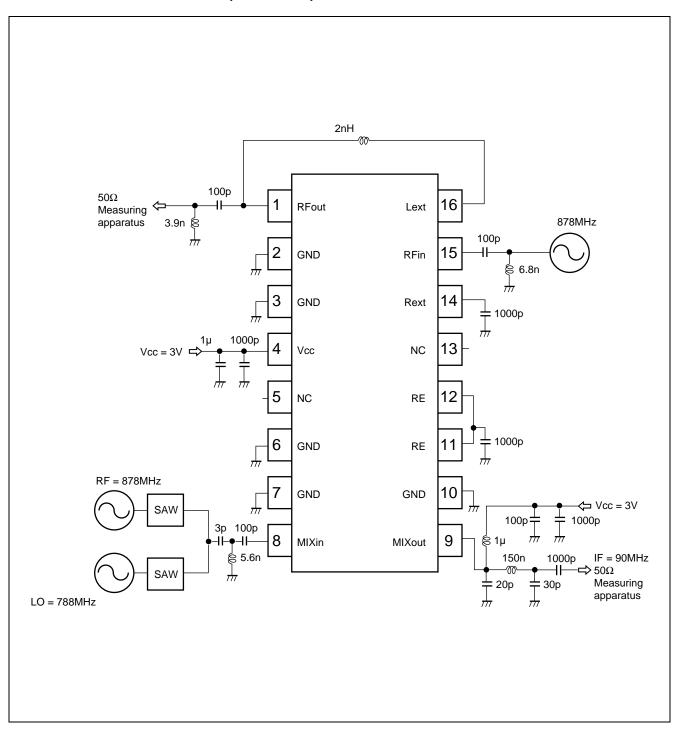
 $(Vcc = +3.0V, Ta = 25^{\circ}C)$ 

Parameter	Symbol	I Conditions		Target Value			l lmit
Parameter	Symbol			Min.	Тур.	Max.	Unit
Supply Voltage	Vcc			2.7	3.0	5.5	V
Current Consumption	Icc				3.0		mA
Operating Frequency	fin				878	1100	MHz
Gain	S <sub>21</sub>	Amplifier characteristics			9		dB
Conversion Gain	Gc	Mixer			15		dB
Noise Figure	NF	characteristics IF = 90MHz	SSB	_	5		dB

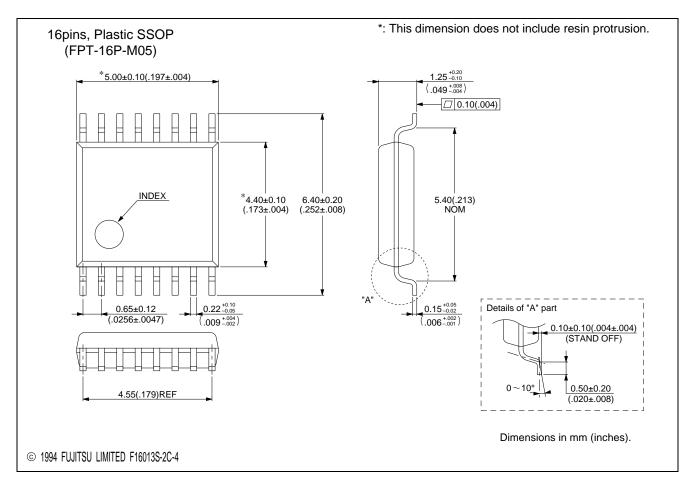
**Remark:** Electrical characteristics depend on external circuits (elements) or status of mounting. The above characteristics are measured by the test circuit in the next page.

# MB54501

## **■ MEASUREMENT CIRCUIT (EXAMPLE)**



## **■ PACKAGE DIMENSIONS**



# **FUJITSU LIMITED**

For further information please contact:

#### **Japan**

FUJITSU LIMITED Corporate Global Business Support Division Electronic Devices KAWASAKI PLANT, 4-1-1, Kamikodanaka Nakahara-ku, Kawasaki-shi Kanagawa 211-8588, Japan

Tel: (044) 754-3763 Fax: (044) 754-3329

http://www.fujitsu.co.jp/

#### **North and South America**

FUJITSU MICROELECTRONICS, INC. Semiconductor Division 3545 North First Street San Jose, CA 95134-1804, USA

Tel: (408) 922-9000 Fax: (408) 922-9179

Customer Response Center Mon. - Fri.: 7 am - 5 pm (PST)

Tel: (800) 866-8608 Fax: (408) 922-9179

http://www.fujitsumicro.com/

#### **Europe**

FUJITSU MIKROELEKTRONIK GmbH Am Siebenstein 6-10 D-63303 Dreieich-Buchschlag Germany

Tel: (06103) 690-0 Fax: (06103) 690-122

http://www.fujitsu-ede.com/

#### **Asia Pacific**

FUJITSU MICROELECTRONICS ASIA PTE LTD #05-08, 151 Lorong Chuan
New Tech Park

Singapore 556741 Tel: (65) 281-0770 Fax: (65) 281-0220

http://www.fmap.com.sg/

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